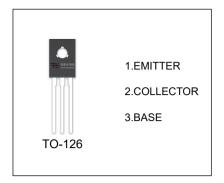


BD135 / BD137 / BD139 TRANSISTOR (NPN)

FEATURES

- High Current
- Complement To BD136, BD138 And BD140



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
BD135	TO-126	Bulk	200pcs/Bag
BD137	TO-126	Bulk	200pcs/Bag
BD139	TO-126	Bulk	200pcs/Bag
BD135-TU	TO-126	Tube	60pcs/Tube
BD137-TU	TO-126	Tube	60pcs/Tube
BD139-TU	TO-126	Tube	60pcs/Tube

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter		Value	Unit	
V _{CBO}		BD135	45	V	
	Collector-Base Voltage	BD137	60		
		BD139	80	1	
		BD135	45		
V_{CEO}	Collector-Emitter Voltage	BD137	60	V	
		BD139	80		
V _{EBO}	Emitter-Base Voltage		5	V	
Ic	Collector Current		1.5	Α	
Pc	Collector Power Dissipation		1.25	W	
R _{0JA}	Thermal Resistance From Junction To Ambient		100	°C/W	
T _J ,T _{stg}	Operation Junction and Storage Temperature Range		-55~+150	$^{\circ}$	



T_a =25 $^{\circ}$ C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = 0.1mA,I _E =0				
BD135			45			V
BD137			60			V
BD139			80			
Collector-emitter sustaining voltage	V _{CEO(SUS)}	I _C =0.03A,I _B =0				
BD135			45			V
BD137			60			V
BD139			80			
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=0.1$ mA, $I_C=0$	5			V
Collector cut-off current	I _{CBO}	V _{CB} =30V,I _E =0			0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} =5V,I _C =0			10	μA
	h _{FE(1)} *	V _{CE} =2V, I _C =150mA	40		250	
DC current gain	h _{FE(2)} *	V _{CE} =2V, I _C =5mA	25			
	h _{FE(3)} *	V _{CE} =2V, I _C =500mA	25			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =500mA,I _B =50mA			0.5	V
Base-emitter voltage	V _{BE}	V _{CE} =2V, I _C =500mA			1	V

^{*}Pulse test: pulse width ≤350µs, duty cycle≤ 2.0%.

CLASSIFICATION OF $h_{\text{FE}(1)}$

RANK	6	10	16
RANGE	40-100	63-160	100-250



